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DOI: 10.48550/arXiv.2304.09665

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Document Version Other version

*Citation for published version (Harvard):* McArdle, G, Davies, R, Lerner, IV & Yurkevich, IV 2023 'Coulomb staircase in an asymmetrically coupled guantum dot' arXiv. https://doi.org/10.48550/arXiv.2304.09665

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### Coulomb staircase in an asymmetrically coupled quantum dot

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**Abstract.** We investigate the Coulomb blockade in quantum dots asymmetrically coupled to the leads for an arbitrary voltage bias focusing on the regime where electrons do not thermalise during their dwell time in the dot. By solving the quantum kinetic equation, we show that the current-voltage characteristics are crucially dependent on the ratio of the Fermi energy to charging energy on the dot. In the standard regime when the Fermi energy is large, there is a Coulomb staircase which is practically the same as in the thermalised regime. In the opposite case of the large charging energy, we identify a new regime in which only one step is left in the staircase, and we anticipate experimental confirmation of this finding.

*Keywords*: Coulomb blockade; quantum dots; non-equilibrium systems; many-body localisation; Keldysh techniques.

Submitted to: J. Phys.: Condens. Matter

#### 1. Introduction

The phenomenon of the Coulomb blockade in quantum dots has been a longstanding topic of interest and many aspects of it have been studied (see [1, 2, 3] for reviews). It arises due to the strong Coulomb interaction resulting in a large charging energy,  $E_c = e^2/C$ , that must be overcome in order to add an additional electron onto the dot of capacitance C. This leads to a number of notable physical results such as peaks in the conductance as a function of gate voltage [4, 5, 6] and a staircase in the dependence of current on the bias voltage (*I-V* characteristics) that has become known as the Coulomb staircase [4, 7, 8].

The conventional approach to the Coulomb blockade is based on the master equation [5, 7, 9, 10], although other approaches have also been successful. For example, the Ambegaokar-Eckern-Schön (AES) action [11] has been used to study relaxation dynamics on a quantum dot [12], although this method cannot be utilised in all regimes [13]. The non-equilibrium Green's function approach has been used to highlight the relation between the Coulomb blockade and the zero-bias anomaly [14, 15, 16, 17], as well as to calculate the tunnelling density of states of a Coulomb-blockaded quantum dot near equilibrium [14, 18].

The master equation approach to the Coulomb staircase assumes instantaneous thermalisation of the tunnelling electrons with those already on the dot. This is justified when the quasiparticle decay rate due to the electron-electron interaction,  $\gamma$ , is much larger than the tunnelling rates to the (left and right) leads,  $\Gamma_{L,R}$ , so that the time spent by the extra electrons on the dot is sufficient for their full thermalisation.

In this paper we consider the regime where one can neglect thermalisation,

$$\gamma \ll \Gamma, \tag{1}$$

otherwise keeping the separation of energy scales characteristic for the classical Coulomb blockade [3]:

$$\Gamma \ll \Delta \ll T \ll E_{\rm c},\tag{2}$$

where  $\Delta$  is the typical energy level spacing and T is the temperature. The regime (1) is important, in particular, when electrons in the dot experience localisation in the Fock space [19] (the precursor for many-body localisation [20]) and is easily reachable in metallic quantum dots with a large dimensionless conductance g. Previously, analytical calculations for this regime have been performed only in the linear response limit [6], while numerical calculations for an arbitrary bias voltage [21] have been limited to the experimentally important regime [22] of a large number of electrons in the dot when  $\varepsilon_{\rm F} \gg E_{\rm c}$  with  $\varepsilon_{\rm F}$  being the electron Fermi energy on the dot. The opposite limit of considerable experimental and theoretical interest is that of a few electrons on the dot, where the lowest energy levels make a strong impact on the observables (see [23] for a review), and the fine structure of the Coulomb staircase is resolved [24].

Here we consider a quantum dot in the absence of thermalisation with strong asymmetry in the coupling to the leads (typically assumed in considerations of the thermalised regime [4, 7, 8, 10]) for both large and small ratio  $\varepsilon_{\rm F}/E_{\rm c}$ . We use the quantum kinetic equation to develop a full analytical solution for the Coulomb staircase for  $N \gg 1$  at any voltage eV and complement it with a numerical solution for  $N \lesssim 10$ .

The solution crucially depends on the ratio  $\varepsilon_{\rm F}/E_{\rm c}$ . For  $\varepsilon_{\rm F} \gg E_{\rm c}$ , the absence of thermalisation does not play a significant role and the Coulomb staircase remains practically the same as in the thermalised regime [4, 7, 8, 10], with an equilibrium established with the most strongly coupled lead.

However, for  $\varepsilon_{\rm F} \ll E_{\rm c}$  we show that the staircase practically vanishes. Instead, assuming the traditional anisotropy in coupling to the leads,  $\Gamma_{\rm R} \ll \Gamma_{\rm L}$ , with the voltage V applied to the left lead, there is a single step in the current equal to  $e\Gamma_{\rm R}(N_0+1)$ (with  $N_0$  being the number of electrons on the dot at V=0) when V increases from 0 to  $eV \sim E_{\rm c}$ . All the further steps are of order 1 in the same units of  $e\Gamma_{\rm R}$ , i.e. practically invisible for  $N \gg 1$ . We have shown numerically that this result holds also for  $N \leq 10$ . This is due to a significant contribution of the low energy levels even for a large number of electrons in the dot.

#### 2. Model

We consider the quantum dot asymmetrically coupled to two leads with the bias voltage V applied to the left one described by the Hamiltonian

$$H = H_{\rm d} + H_\ell + H_{\rm T} \,. \tag{3}$$

Here  $H_d$  is the Hamiltonian of the Coulomb-blockaded dot in the zero-dimensional limit [1, 2, 3],

$$H_{\rm d} = \sum_{n} \varepsilon_n d_n^{\dagger} d_n + \frac{1}{2} E_{\rm c} \left( \hat{N} - N_{\rm g} \right)^2, \tag{4}$$

where  $\varepsilon_n$  are the energy levels of the dot,  $d_n^{\dagger}(d_n)$  are the creation (annihilation) operators of the quantum dot,  $\hat{N} = \sum_n d_n^{\dagger} d_n$  is the number operator for the dot, and  $N_{\rm g}$  is the preferable number of electrons on the dot in equilibrium set by the gate voltage. The coupling to the leads is described by

$$H_{\ell} = \sum_{k,\alpha} \left( \varepsilon_k - \mu_{\alpha} \right) c_{k,\alpha}^{\dagger} c_{k,\alpha}, \tag{5}$$

where  $\alpha = L$ , R labels the lead,  $c_{k,\alpha}^{\dagger}(c_{k,\alpha})$  are the creation (annihilation) operators for an electron of energy  $\varepsilon_k$ , and  $\mu_{\alpha}$  is the chemical potential of the lead,  $\mu_{\rm L} = \mu + eV$  and  $\mu_{\rm R} = \mu$ . The tunnelling between the dot and the leads is described by the tunnelling Hamiltonian

$$H_{\rm T} = \sum_{\alpha,k,n} \left( t_{\alpha} c_{k,\alpha}^{\dagger} d_n + \text{h.c.} \right), \tag{6}$$

where the tunnelling amplitude  $t_{\alpha}$ , which is assumed to be independent of k and n, defines the broadening of the energy levels  $\Gamma = \Gamma_{\rm L} + \Gamma_{\rm R}$  with  $\Gamma_{\alpha} = 2\pi\nu_{\alpha}|t_{\alpha}|^2$ , with the density of states  $\nu_{\alpha}$  taken to be a constant.

Coulomb staircase in an asymmetrically coupled quantum dot

We assume the absence of thermalisation in the dot which will allow us to use the quantum kinetic equation for a given energy. This is justified when the inequality (1) is satisfied. For a zero-dimensional diffusive dot, the quasiparticle decay rate due to the electron-electron interaction at energy  $\varepsilon$  is given for  $\Delta \ll T$  by [19, 25, 26]

$$\gamma(\varepsilon) \approx \Delta \left(\frac{\varepsilon}{E_{\rm Th}}\right)^2,$$
(7)

where  $E_{\rm Th} = g\Delta$  is the Thouless energy and  $g \gg 1$  is the dimensionless conductance of the dot. This result is valid provided that  $\sqrt{g}\Delta < \varepsilon < E_{\rm Th}$ .

In the equilibrium regime in the absence of the coupling to the leads, the tunnelling density of states has some interesting features [18] which, intuitively, are preserved if one lead dominates the behaviour of the system and the chemical potential on the dot will be determined by that lead. This quasi-equilibration allows us to solve exactly the case of strongly asymmetrically coupled leads, either for  $\Gamma_{\rm L}/\Gamma_{\rm R} \gg 1$  when the jumps in the current exist, or for  $\Gamma_{\rm L}/\Gamma_{\rm R} \ll 1$  when the current has almost Ohmic behaviour.

#### 3. Quantum kinetic equation

To analyse the Coulomb blockaded quantum dot in the non-linear regime we use the Keldysh technique (see, e.g., [27] for a review) in a way similar to that detailed in [28].

#### 3.1. Quantum dot in the weak coupling limit

In the case of an isolated dot, i.e. totally neglecting the level broadening  $\Gamma$ , the Keldysh Green's function can be written as a sum over all levels,  $g^{>,<}(\varepsilon) = \sum_n g_n^{>,<}(\varepsilon)$  with the single-level Green's functions given by

$$g_n^{>}(t) = -i \operatorname{Tr} \left( \hat{\rho}_0 d_n(t) d_n^{\dagger} \right), \quad g_n^{<}(t) = -i \operatorname{Tr} \left( \hat{\rho}_0 d_n^{\dagger} d_n(t) \right), \tag{8}$$

where  $d_n(t) = e^{iHt} d_n e^{-iHt}$  and  $\hat{\rho}_0$  is the density matrix. Additionally, the particle number is conserved and the Green's functions can be written as sums over the *N*-particle subspaces,

$$g_n^{>}(\varepsilon) = -2\pi i \sum_N \delta\left(\varepsilon - \varepsilon_n - \Omega_N\right) g_N^{>}(\varepsilon_n), \qquad g_N^{>}(\varepsilon_n) = \operatorname{Tr}_N\left(\hat{\rho}_0 d_n d_n^{\dagger}\right), \tag{9}$$

$$g_n^{<}(\varepsilon) = -2\pi i \sum_N \delta\left(\varepsilon - \varepsilon_n - \Omega_{N-1}\right) g_N^{<}(\varepsilon_n), \quad g_N^{<}(\varepsilon_n) = -\operatorname{Tr}_N\left(\hat{\rho}_0 d_n^{\dagger} d_n\right), \tag{10}$$

with the normalisation  $\sum_{N} (g_{N}^{>}(\varepsilon_{n}) - g_{N}^{<}(\varepsilon_{n})) = 1$ . The charging energy required to add an electron is included above through  $\Omega_{N}$  defined as

$$\Omega_N \equiv E_{N+1} - E_N = E_{\rm c} \Big( N + \frac{1}{2} - N_{\rm g} \Big), \qquad E_N \equiv \frac{1}{2} E_{\rm c} (N - N_{\rm g})^2.$$
(11)

The coupling to the leads is included via the quantum kinetic equation (QKE), which in the weak coupling limit ( $\Gamma \rightarrow 0$ ) can be written for each level as [28, 29]

$$g_n^{>,<}(\varepsilon) = g_n^{\mathrm{R}}(\varepsilon) \Sigma^{>,<}(\varepsilon) g_n^{\mathrm{A}}(\varepsilon) .$$
(12)

The self energies for non-interacting leads are assumed to be independent of the dot level n and are given by

$$\Sigma^{>}(\varepsilon) = \sum_{k,\alpha} |t_{\alpha}|^{2} g_{k,\alpha}^{>}(\varepsilon) = -i \left[ \Gamma - \left( \Gamma_{\rm L} f_{\rm L}(\varepsilon) + \Gamma_{\rm R} f_{\rm R}(\varepsilon) \right) \right], \tag{13}$$

$$\Sigma^{<}(\varepsilon) = \sum_{k,\alpha} |t_{\alpha}|^{2} g_{k,\alpha}^{<}(\varepsilon) = i \left( \Gamma_{\rm L} f_{\rm L}(\varepsilon) + \Gamma_{\rm R} f_{\rm R}(\varepsilon) \right).$$
(14)

Above, the Green's functions for the leads are  $g_{k,\alpha}^{>}(\varepsilon) = -2\pi i (1 - f(\varepsilon - \mu_{\alpha})) \delta(\varepsilon - \varepsilon_k + \mu_{\alpha})$ and  $g_{k,\alpha}^{<}(\varepsilon) = 2\pi i f(\varepsilon - \mu_{\alpha}) \delta(\varepsilon - \varepsilon_k + \mu_{\alpha})$ , where  $f(\varepsilon - \mu_{\alpha})$  is a Fermi function. The density of states in the leads, which enters via the tunnelling rates  $\Gamma_{\alpha} = 2\pi \nu_{\alpha} |t_{\alpha}|^2$ , is given by  $\nu_{\alpha} = \sum_k \delta(\varepsilon - \varepsilon_k + \mu_{\alpha})$ , while  $\Gamma = \Gamma_{\rm L} + \Gamma_{\rm R}$ .

Now we rewrite the QKE (12) as

$$g_n^{>}(\varepsilon)\Sigma^{<}(\varepsilon) = g_n^{<}(\varepsilon)\Sigma^{>}(\varepsilon).$$
(15)

Substituting in Eqs. (9, 10) we use the ansatz

$$g_N^{>}(\varepsilon_n) = p_N \left(1 - F_N(\varepsilon_n)\right) \quad \text{and} \quad g_N^{<}(\varepsilon_n) = -p_N F_N(\varepsilon_n),$$
(16)

where  $p_N$  is the probability of having N electrons on the dot and  $F_N(\varepsilon_n)$  is the distribution function given N electrons on the dot which, in the case of complete thermalisation, goes over to the equilibrium Fermi distribution function. In these terms, we write the QKE as follows:

$$p_N \left(1 - F_N(\varepsilon_n)\right) \widetilde{f}(\varepsilon_n + \Omega_N) = p_{N+1} F_{N+1}(\varepsilon_n) \left(1 - \widetilde{f}(\varepsilon_n + \Omega_N)\right), \quad (17)$$

where

$$\widetilde{f}(\varepsilon) = \frac{\Gamma_{\rm L}}{\Gamma} f(\varepsilon - \mu - eV) + \frac{\Gamma_{\rm R}}{\Gamma} f(\varepsilon - \mu).$$
(18)

This corresponds to the detailed balance equations derived in [6] for  $\Delta \gg T$  and reproduces the case of complete thermalisation after the summation over n and making the replacement  $F_N(\varepsilon) \to f(\varepsilon - \varepsilon_{\rm F})$ . The QKE (17) should be complemented by the normalisation conditions,  $\sum_N p_N = 1$  and  $\sum_n F_N(\varepsilon_n) = N$ .

We represent the current going from the dot to the lead 
$$\alpha$$
 via  $p_N$  and  $F_N(\varepsilon_n)$  as  

$$I_{\alpha} = e\Gamma_{\alpha} \sum_{N} p_N \sum_{n} \left( F_N(\varepsilon_n) \left[ 1 - f(\varepsilon_n - \mu_{\alpha} + \Omega_{N-1}) \right] - \left[ 1 - F_N(\varepsilon_n) \right] f(\varepsilon_n - \mu_{\alpha} + \Omega_N) \right) (19)$$

Applying current conservation,  $I = I_R = -I_L$  and using  $\mu_L = \mu + eV$  and  $\mu_R = \mu$ , we express the current as

$$I = e \frac{\Gamma_{\rm L} \Gamma_{\rm R}}{\Gamma} \sum_{N} p_N \sum_{n} \left( F_N(\varepsilon_n) \left[ f(\varepsilon_n - \mu_{N-1} - eV) - f(\varepsilon_n - \mu_{N-1}) \right] + (1 - F_N(\varepsilon_n)) \left[ f(\varepsilon_n - \mu_N - eV) - f(\varepsilon_n - \mu_N) \right] \right).$$
(20)

with  $\mu_N \equiv \mu - \Omega_N$ . Assuming a density of states on the dot to be constant,  $1/\Delta$ , we convert the sum over *n* to an integral over all energies on the dot (counted from zero). Then in the low-*T* limit

$$I = e \frac{\Gamma_{\rm L} \Gamma_{\rm R}}{\Gamma} \sum_{N} p_N \bigg[ \int_{\mu_{N-1}}^{\mu_{N-1} + eV} \mathrm{d}\varepsilon \,\Theta(\varepsilon) F_N(\varepsilon) + \int_{\mu_N}^{\mu_N + eV} \mathrm{d}\varepsilon \,\Theta(\varepsilon) (1 - F_N(\varepsilon)) \bigg], \tag{21}$$

where  $\Theta(\varepsilon)$  is the Heaviside step function.

#### 3.2. Solution to the QKE

The charging energy strongly penalises states with a wrong number of electrons on the dot. In the case of strongly asymmetric leads with  $\Gamma_{\rm L} \gg \Gamma_{\rm R}$ , the main contribution to (20) is given by the two states with N closest to  $N_{\rm g} + eV/E_{\rm c}$ , since electrons have time to fill the dot up. In the opposite case,  $\Gamma_{\rm L} \ll \Gamma_{\rm R}$ , the two relevant states are those closest to  $N_{\rm g}$ . Keeping only the appropriate two states in the QKE (17) allows us to obtain the following exact solution:

$$p_N = \frac{Z_N}{Z_N + Z_{N+1}}, \qquad p_{N+1} = \frac{Z_{N+1}}{Z_N + Z_{N+1}},$$

$$F_N(\varepsilon_n) = \frac{Z_N(\varepsilon_n)}{Z_N}, \qquad F_{N+1}(\varepsilon_n) = \frac{Z_{N+1}(\varepsilon_n)}{Z_{N+1}},$$
(22)

where

$$Z_N = \sum_{\{n_j=0,1\}} \prod_{j=1}^{\infty} \left[ \varphi(\varepsilon_j + \Omega_N) \right]^{n_j} \delta_{(\sum_j n_j),N},$$
  

$$Z_{N+1} = \sum_{\{n_j=0,1\}} \prod_{j=1}^{\infty} \left[ \varphi(\varepsilon_j + \Omega_N) \right]^{n_j} \delta_{(\sum_j n_j),N+1},$$
(23)

with functions  $\varphi$  defined via  $\tilde{f}$  in (18) as

$$\varphi(\varepsilon_j + \Omega_N) = \frac{\widetilde{f}(\varepsilon_j + \Omega_N)}{1 - \widetilde{f}(\varepsilon_j + \Omega_N)},\tag{24}$$

while  $Z_N(\varepsilon_n)$  in (22) is defined by restricting the sums in (23) to configurations with the state  $\varepsilon_n$  occupied. It is important to highlight that due to the form of the QKE (17),  $Z_{N+1}$  in (23) contain  $\Omega_N$  rather than  $\Omega_{N+1}$  so that the relevant N dependence enters only in the Krönecker delta.

When  $N \gg 1$ , the Krönecker delta is equivalent to a delta function,

$$\delta_{(\sum_{j} n_{j}),N} = \int \frac{\mathrm{d}\theta}{2\pi} \mathrm{e}^{i\theta\left(\sum_{j} n_{j} - N\right)},\tag{25}$$

which allows us to write the sums in (23) in the form

$$Z_N = \int \frac{\mathrm{d}\theta}{2\pi} \mathrm{e}^{Nf(\theta)}, \qquad f(\theta) = \frac{1}{N} \sum_j \ln\left(1 + \varphi(\varepsilon_j + \Omega_N)\mathrm{e}^{i\theta}\right) - i\theta. \tag{26}$$

Now  $Z_N$  can be evaluated in the saddle-point approximation. The optimal  $\theta_0$  is found from the second equation above where the sum is converted to the integral,  $\sum_i \to \Delta^{-1} \int_0^\infty d\varepsilon$ , which gives

$$\varepsilon_{\rm F} = N\Delta = \int_0^\infty \mathrm{d}\varepsilon \left(\frac{\mathrm{e}^{-i\theta_0}}{\varphi(\varepsilon + \Omega_N)} + 1\right)^{-1}.$$
 (27)

As  $\Omega_N$  is unchanged by definition when going between  $Z_N$  and  $Z_{N+1}$ , (23), the relevant N dependence of  $\theta_0$  enters only via  $\varepsilon_{\rm F} = N\Delta$ . Thus we find that in the saddle-point approximation  $Z_N = g(\theta_0) e^{-iN\theta_0}$ , where  $g(\theta_0)$  is a function which depends on N only

$$\frac{p_{N+1}}{p_N} = e^{-i\theta_0}, \quad F_N(\varepsilon_n) \approx F_{N+1}(\varepsilon_n) \approx \left(\frac{e^{-i\theta_0}}{\varphi(\varepsilon + \Omega_N)} + 1\right)^{-1}.$$
 (28)

The ratio of probabilities can be found by using  $N = \sum_{n} F_N(\varepsilon_n)$ , which corresponds to the saddle point equation above.

The resulting I-V characteristics turn out to be strikingly different for the two opposite regimes, when the ratio  $\varepsilon_{\rm F}/E_{\rm c}$  is either small or large, as described in the following section.

#### 4. Results and Discussion

We begin by reproducing the well-known results of the standard theory for  $\varepsilon_{\rm F} \gg E_{\rm c}$  to show that (i) our approach works and (ii) the absence of the full thermalisation does not make a significant impact on the Coulomb staircase in the case of strong asymmetry in the coupling to the leads.

Then we show that in the opposite limit,  $\varepsilon_{\rm F} \ll E_{\rm c}$ , there is only one significant step left in the Coulomb staircase if  $N \gg 1$ . Additionally, we present numerical results for small N which are in full agreement with our analytical results for  $N \gg 1$ .

#### 4.1. Small charging energy, $E_{\rm c} \ll \varepsilon_{\rm F}$

We start with the linear response regime. Then  $\tilde{f}(\varepsilon) \to f(\varepsilon - \mu)$  in (18) so that  $\varphi(\varepsilon + \Omega_N) \to \exp[-\beta(\varepsilon - \mu + \Omega_N)]$  in (24). Hence, using (28) we reduce the saddle point equation (27) to

$$\varepsilon_{\rm F} = \int_0^\infty \frac{\mathrm{d}\varepsilon}{\mathrm{e}^{\beta(\varepsilon-\mu_N)-i\theta_0}+1} = T \ln\left(\mathrm{e}^{\beta\mu_N+i\theta_0}+1\right) \approx \mu_N + i\theta_0 T,\tag{29}$$

where the approximate equality holds in the low-temperature limit,  $\beta \mu_N + i\theta_0 \gg 1$ . Substituting into (28)  $i\theta_0 = \beta(\varepsilon_{\rm F} - \mu_N) = \beta(\varepsilon_{\rm F} - \mu + \Omega_N)$  (with  $\mu$  being the chemical potential in the leads and  $\varepsilon_{\rm F}$  in the dot), and using  $p_N + p_{N+1} \approx 1$  results in the following expressions for the probabilities and distribution function,

$$p_N = \frac{\mathrm{e}^{-\beta(E_N + N(\varepsilon_{\mathrm{F}} - \mu))}}{\sum_N \mathrm{e}^{-\beta(E_N + N(\varepsilon_{\mathrm{F}} - \mu))}}, \quad F_N(\varepsilon) = \frac{1}{\mathrm{e}^{\beta(\varepsilon - \varepsilon_{\mathrm{F}})} + 1}, \tag{30}$$

where the sum over N is restricted to the two states with N closest to  $N_{\rm g}$ . Substituting (30) into the current (20) results in the following shape of the differential conductance near the peak,  $\mu - \Omega_N - \varepsilon_{\rm F} = 0$ :

$$G = \frac{\mathrm{d}I}{\mathrm{d}V} = \frac{e^2}{2\Delta} \frac{\Gamma_{\mathrm{L}}\Gamma_{\mathrm{R}}}{\Gamma} \frac{\frac{\beta}{2}(\Omega_N + \varepsilon_{\mathrm{F}} - \mu)}{\sinh(\frac{\beta}{2}(\Omega_N + \varepsilon_{\mathrm{F}} - \mu))},\tag{31}$$

in agreement with [4, 6].

We now turn to the nonlinear regime and demonstrate, by reproducing the wellknown results [4, 7, 8] for strongly asymmetric coupling to the leads and  $\varepsilon_{\rm F} \gg E_{\rm c}$ , that the absence of thermalisation has no impact on the Coulomb staircase. For  $\Gamma_{\rm L} \gg \Gamma_{\rm R}$ , the solution to the QKE (17) for any V is given by (30) provided that we replace  $\mu$  by  $\mu_{\rm L} \equiv \mu + eV$  and restrict the sum over N to the two states with N closest to  $N_{\rm g} + eV/E_{\rm c}$ . Due to the exponential forms of the probabilities in (30), only one such state contributes to the current outside some narrow windows in V. For a given V, this is the state where N obeys the inequality  $\Omega_{N-1} \leq eV \leq \Omega_N$ . Noticing that the distribution function in (30),  $F_N(\varepsilon) = f(\varepsilon - \varepsilon_{\rm F})$ , is a Fermi function with a chemical potential  $\varepsilon_{\rm F}$ , we see that the second integral in (21) does not contribute to the current for low T, as the upper limit of integration  $\mu_N + eV \approx \varepsilon_{\rm F} - (\Omega_N - eV) < \varepsilon_{\rm F}$ .

Consider the contribution of the first integral in (21), starting with the regime that begins in equilibrium (V = 0) and continues for  $0 \le eV \lesssim \Omega_{N_0}$ , when there are  $N_0$  electrons on the dot. Then, as  $\Omega_{N_0} \approx E_c/2$  the lower integration limit  $\mu_{N_0-1} \equiv \mu - \Omega_{N_0-1} \approx \varepsilon_F + E_c/2 > \varepsilon_F$  so that this integral also vanishes. The current is therefore zero as expected. With V increasing beyond  $\Omega_{N_0}$ , there are  $N > N_0$  electrons on the dot. In this case, having  $\varepsilon_F \gg E_c$  ensures that  $\varepsilon_F > \Omega_N$  for all relevant  $\Omega_N$  and both the integration limits are positive, so the presence of  $\Theta(\varepsilon)$  is irrelevant. The steps in the current in the low-T limit are, therefore, given by

$$I = 0, \qquad 0 \le eV \lesssim \Omega_{N_0} \qquad (p_{N_0} = 1),$$
  

$$I = e\Gamma_{\mathrm{R}} \frac{\Omega_{N_0}}{\Delta}, \qquad \Omega_{N_0} \lesssim eV \lesssim \Omega_{N_0+1} \qquad (p_{N_0+1} = 1), \qquad (32)$$
  

$$I = e\Gamma_{\mathrm{R}} \frac{\Omega_{N_0+1}}{\Delta}, \qquad \Omega_{N_0+1} \lesssim eV \lesssim \Omega_{N_0+2} \qquad (p_{N_0+2} = 1),$$

and so on. This demonstrates a staircase structure with the steps separated by  $eV=E_{\rm c}$ and an almost constant height proportional to  $E_{\rm c}/\Delta$ . The full results, including the windows around the jumps at  $eV=\Omega_N$ , are obtained by substituting (30) with the change



Figure 1. The *I-V* characteristics for a dot in the regime where  $N_0 \Delta \gg E_c (N_0 \Delta = 10E_c)$  and  $\Omega_{N_0} = E_c/2$ . The blue line represents our solution to the QKE and the black dashed line is the solution to the master equation in the standard theory where full thermalisation is assumed [4, 7, 8]. In both instances, (a):  $\Gamma_L/\Gamma_R = 10^3$  and (b):  $\Gamma_L/\Gamma_R = 10^{-3}$  an equilibrium is set up with the dominant lead and the approaches produce the same results.

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 $\mu \to \mu_{\rm L}$  into (20) and are practically indistinguishable from the full thermalisation case [4, 7, 8], as shown in Figure 1(a).

For the opposite asymmetry,  $\Gamma_{\rm R} \gg \Gamma_{\rm L}$ , equilibrium with the right lead (with no voltage applied there) is maintained and no staircase is observed as  $p_{N_0} \approx 1$  for all values of V. Instead, the Ohmic behaviour prevails for  $eV \gtrsim \Omega_{N_0}$  as the tunnelling electron gains more energy as shown in Figure 1(b).

#### 4.2. Large charging energy, $E_{\rm c} \gg \varepsilon_{\rm F}$

In this limit, the low-energy states in the dot make a considerable impact on the transport behaviour. The reason is that the regime  $\varepsilon_{\rm F} < \Omega_N$ , which was impossible  $\varepsilon_{\rm F}/E_{\rm c} \gg 1$ , now arises.

For  $\Gamma_{\rm L} \gg \Gamma_{\rm R}$ , the expressions for  $p_N$  and  $F_N(\varepsilon)$  are formally the same as for  $E_{\rm c} \ll \varepsilon_{\rm F}$  in (30) with the substitution  $\mu \to \mu_{\rm L}$ . However, as  $F_N(\varepsilon)$  is now an extremely narrow function (on the scale of  $E_{\rm c}$ ) and the integration limits may be negative, the contributions of the above integrals to the current are severely restricted in comparison to the case of  $\varepsilon_{\rm F}/E_{\rm c} \gg 1$ . Starting again with  $N_0$  electrons on the dot at equilibrium, we make similar arguments as in the former case to see that only the first integral in (21) contributes. The crucial difference for  $N > N_0$  is that the lower limit of integration,  $\mu_{N-1} \approx \varepsilon_{\rm F} - \Omega_{N-1} = N\Delta - \Omega_{N-1}$ , is less than zero, so that  $\Theta(\varepsilon)$  becomes relevant. Therefore, we find the current in the low-T limit to be strikingly different from that in (32). (Note that for the opposite asymmetry,  $\Gamma_{\rm R} \gg \Gamma_{\rm L}$ , the current remains Ohmic for any ratio  $\varepsilon_{\rm F}/E_{\rm c}$ .)

$$I = 0, 0 \le eV \lesssim \Omega_{N_0} (p_{N_0} = 1), I = e\Gamma_{\rm R}(N_0 + 1), \Omega_{N_0} \lesssim eV \lesssim \Omega_{N_0 + 1} (p_{N_0 + 1} = 1), (33) I = e\Gamma_{\rm R}(N_0 + 2), \Omega_{N_0 + 1} \lesssim eV \lesssim \Omega_{N_0 + 2} (p_{N_0 + 2} = 1),$$



Figure 2. The numerical *I*-V characteristics for a dot with 7 states in the regime where  $N_0 \Delta \ll E_c$  $(N_0 \Delta \approx 0.01 E_c)$  and  $\Omega_{N_0} = E_c/2$ . (a): Increasing the charging energy makes the steps sharper but does not affect the size of the jumps. (b): Increasing the number,  $N_0$ , of electrons in equilibrium (with the gate voltage) illustrates that the first jump is equal to  $e\Gamma_R(N_0+1)$ . In both cases  $\Gamma_L = 100\Gamma_R$ .

and so on. Crucially the first jump in the current (measured in units of  $e\Gamma_{\rm R}$ ) at  $eV = \Omega_{N_0}$ is equal to  $N_0 + 1$  while all the subsequent jumps equal to 1 in these units.

For  $N_0 \gg 1$ , this means that the staircase practically disappears beyond the first step in contrast to the constant jumps of size  $E_c/\Delta$  for large  $N_0\Delta$ , see (32). Although we have performed analytical calculations for  $N_0 \gg 1$ , the results for  $\varepsilon_F \ll E_c$  turn out to be exactly the same for small  $N_0$  given a constant charging energy. We demonstrate this by numerically solving the quantum master equation [30] under the conditions (1), (2), for a dot with 7 levels. The results are shown in Figure 2. While all the steps there are pronounced, all but the first one would practically disappear for  $N_0 \gg 1$ .

#### 5. Conclusion

To summarise, we have analytically calculated I-V characteristics of the quantum dot with a strong asymmetry in the tunnelling coupling to the leads in the Coulomb blockade regime (2) in the absence of thermalisation (1). We have solved the appropriate quantum kinetic equation in the two limits, for either a large or small ratio,  $E_c/\varepsilon_F$ , of the charging energy to the Fermi energy of electrons in the dot.

We have demonstrated that for a relatively small charging energy,  $E_c/\varepsilon_F \ll 1$ , the absence of thermalisation in a quantum dot has practically no impact on the Coulomb staircase as an equilibrium is established between the dot and the most strongly coupled lead, see Figure 1. This is in agreement with previous numerical results [21] which assume the distribution function is the same for all relevant N. We have verified this assumption in the large N limit when no more than two states are relevant in (28).

In the opposite limit,  $E_c/\varepsilon_F \gg 1$ , we have analytically shown that for  $N \gg 1$  the Coulomb staircase has only one pronounced step. With a voltage V applied to the left lead and  $\Gamma_L/\Gamma_R \gg 1$ , this is a step in the current from 0 to  $e\Gamma_R(N_0 + 1)$  in a narrow window around  $eV = \Omega_{N_0}$  with  $\Omega_{N_0} = E_c/2$  if  $N_0 = N_g$ , see (11). All the subsequent current jumps with V increasing have the magnitude  $e\Gamma_R$ , see (33), i.e. negligible when the number of electrons at equilibrium  $N_0 \gg 1$ . Further to the analytic results, we have numerically solved the quantum master equation for a constant  $E_c$  to find that the analytical results (33) proven for  $N \gg 1$  are exactly valid also in the experimentally attractive regime of  $N \leq 10$ , see Figure 2. The reason for such behaviour of the Coulomb staircase is that the only electrons available for tunnelling are those in an energy window  $\sim \varepsilon_F$  with the voltage window being much larger,  $eV \sim E_c$ . With  $\varepsilon_F/E_c$  increasing, more electrons are available for tunnelling, thus restoring the jumps between the steps to their full value  $\propto E_c/\Delta$  in the usual regime  $\varepsilon_F \gg E_c$  [4, 7, 8] where electrons from the entire voltage window contribute to the current.

#### Acknowledgements

We gratefully acknowledge support from EPSRC under the grant EP/R029075/1 (IVL) and from the Leverhulme Trust under the grant RPG-2019-317 (IVY).

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